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Vishay Semiconductors

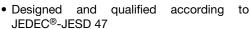
Fast Soft Recovery Rectifier Diode, 40 A



PRIMARY CHARACTERISTICS					
I _{F(AV)}	40 A				
V _R	1000 V, 1200 V				
V _F at I _F	1.4 V				
I _{FSM}	475 A				
t _{rr}	95 ns				
T _J max.	150 °C				
Package	TO-247AC 2L				
Circuit configuration	Single				
Snap factor	0.5				

FEATURES

- Glass passivated pellet chip junction
- 150 °C max. operating junction temperature
- Low forward voltage drop and short reverse recovery time







APPLICATIONS

These devices are intended for use in output rectification and freewheeling in inverters, choppers and converters as well as in input rectification where severe restrictions on conducted EMI should be met.

DESCRIPTION

The VS-45EPF12L-M3, VS-45APF12L-M3 fast soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
V _{RRM}		1000/1200	V		
I _{F(AV)}	Sinusoidal waveform	40	^		
I _{FSM}		475	Α Α		
t _{rr}	1 A, 100 A/µs	95	ns		
V _F	20 A, T _J = 25 °C	1.25	V		
T _J		-40 to +150	°C		

VOLTAGE RATINGS					
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA		
VS-40EPF10-M3	1000	1100	10		
VS-40EPF12-M3	1200	1300	10		

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum average forward current	I _{F(AV)}	T _C = 105 °C, 180° conduction half sine wave	40		
Maximum peak one cycle non-repetitive surge current		10 ms sine pulse, rated V _{RRM} applied	400	Α	
	I _{FSM}	10 ms sine pulse, no voltage reapplied	475		
Maximum I ² t for fusing I ² t	124	10 ms sine pulse, rated V _{RRM} applied	800 A ² s		
	i-t	10 ms sine pulse, no voltage reapplied	1131	A-5	
Maximum I ² √t for fusing	I²√t	t = 0.1 ms to 10 ms, no voltage reapplied	11 310	A²√s	



ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	V_{FM}	40 A, T _J = 25 °C		1.4	V
Forward slope resistance	r _t	- T _J = 150 °C		6.82	mΩ
Threshold voltage	V _{F(TO)}			0.94	V
Maximum reverse leakage current		T _J = 25 °C	V _R = Rated V _{RRM}	0.1	mA
Maximum reverse leakage current	I _{RM}	T _J = 150 °C		10	IIIA

RECOVERY CHARACTERISTICS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	. •
Reverse recovery time	t _{rr}	In at 10 Anu	450	ns	I _{FM} +
Reverse recovery current	I _{rr}	I _F at 10 A _{pk} 25 A/μs	6	Α	
Reverse recovery charge	Q _{rr}	25 °C	1.8	μC	dir/ Q _{rr}
Snap factor	S		0.5		I _{RM(REC)}

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and sto temperature range	orage	T _J , T _{Stg}		-40 to +150	°C
Maximum thermal resistar junction to case	nce,	R _{thJC}	DC operation	0.6	
Maximum thermal resistance, junction to ambient		R _{thJA}		40	°C/W
Typical thermal resistance case to heatsink	·,	R _{thCS}	Mounting surface, smooth and greased	0.2	
Approximate weight				6	g
Approximate weight	Approximate weight			0.21	OZ.
Manustina tanana	minimum			6 (5)	kgf · cm
Mounting torque m	maximum			12 (10)	(lbf ⋅ in)
Marking device			O TO 04740 01	40EPF10	
			Case style TO-247AC 2L	40EPF12	



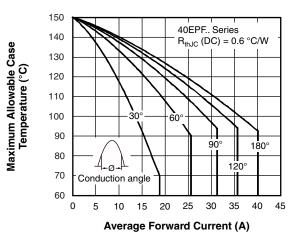


Fig. 1 - Current Rating Characteristics

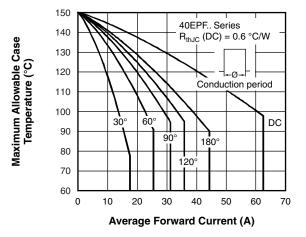


Fig. 2 - Current Rating Characteristics

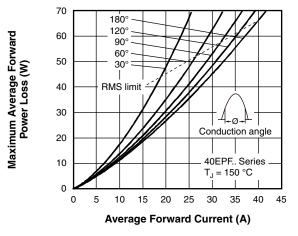


Fig. 3 - Forward Power Loss Characteristics

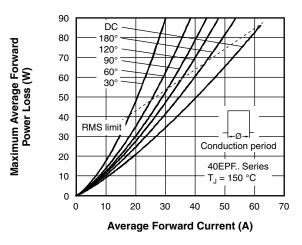


Fig. 4 - Forward Power Loss Characteristics

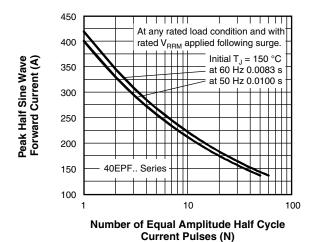


Fig. 5 - Maximum Non-Repetitive Surge Current

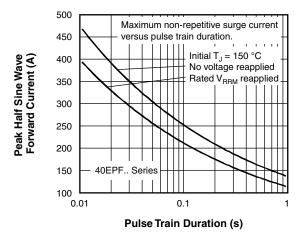


Fig. 6 - Maximum Non-Repetitive Surge Current

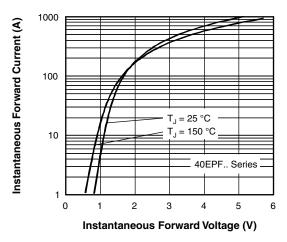


Fig. 7 - Forward Voltage Drop Characteristics

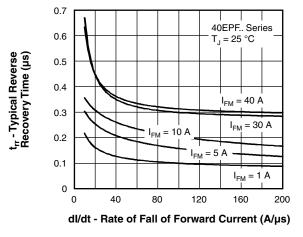


Fig. 8 - Recovery Time Characteristics, $T_J = 25$ °C

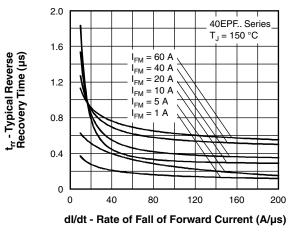


Fig. 9 - Recovery Time Characteristics, $T_J = 150~^{\circ}\text{C}$

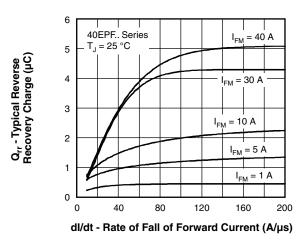


Fig. 10 - Recovery Charge Characteristics, T_J = 25 °C

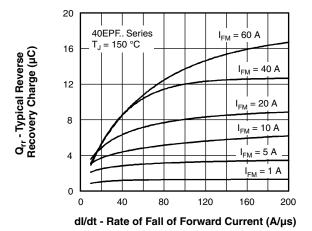
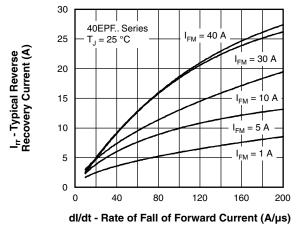


Fig. 11 - Recovery Charge Characteristics, $T_J = 150 \, ^{\circ}\text{C}$



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50 40EPF.. Series T_J = 150 °C = 60 A40 I_{rr} - Typical Reverse Recovery Current (A) 30 = 20 A 20 $I_{FM} = 5 A$ 10 0 0 40 80 120 160 200 dl/dt - Rate of Fall of Forward Current (A/µs)

Fig. 12 - Recovery Current Characteristics, $T_J = 25~^{\circ}\text{C}$

Fig. 13 - Recovery Current Characteristics, T_J = 150 °C

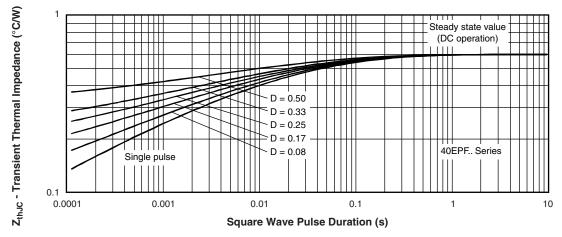
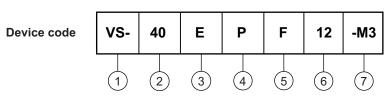


Fig. 14 - Thermal Impedance Z_{thJC} Characteristics



ORDERING INFORMATION TABLE



1 - Vishay Semiconductors product

2 - Current rating (40 = 40 A)

Circuit configuration:

E = single diode

4 - Package:

P = TO-247AC 2L

5 - Type of silicon:

F = fast recovery

6 - Voltage code x 100 = V_{RRM} 10 = 1000 V 12 = 1200 V

7 - Environmental digit:

-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-40EPF10-M3	25	500	Antistatic plastic tubes		
VS-40EPF12-M3	25	500	Antistatic plastic tubes		

LINKS TO RELATED DOCUMENTS			
Dimensions <u>www.vishay.com/doc?96144</u>			
Part marking information	www.vishay.com/doc?95648		



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